Unitrode Products from Texas Instruments 勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



UC1825 UC2825 UC3825

High Speed PWM Controller

FEATURES

DESCRIPTION

- Compatible with Voltage or Current Mode Topologies
- Practical Operation Switching Frequencies to 1MHz
- 50ns Propagation Delay to Output
- High Current Dual Totem Pole Outputs (1.5A Peak)
- Wide Bandwidth Error Amplifier
- Fully Latched Logic with Double Pulse Suppression
- Pulse-by-Pulse Current Limiting
- Soft Start / Max. Duty Cycle Control
- Under-Voltage Lockout with Hysteresis
- Low Start Up Current (1.1mA)

The UC1825 family of PWM control ICs is optimized for high frequency switched mode power supply applications. Particular care was given to minimizing propagation delays through the comparators and logic circuitry while maximizing bandwidth and slew rate of the error amplifier. This controller is designed for use in either current-mode or voltage mode systems with the capability for input voltage feed-forward.

Protection circuitry includes a current limit comparator with a 1V threshold, a TTL compatible shutdown port, and a soft start pin which will double as a maximum duty cycle clamp. The logic is fully latched to provide jitter free operation and prohibit multiple pulses at an output. An under-voltage lockout section with 800mV of hysteresis assures low start up current. During under-voltage lockout, the outputs are high impedance.

These devices feature totem pole outputs designed to source and sink high peak currents from capacitive loads, such as the gate of a power MOSFET. The on state is designed as a high level.



BLOCK DIAGRAM



THERMAL RATINGS TABLE

Package	ΘJA	οJC
DIL-16J	80-120	28 ⁽²⁾
DIL-16N	90 ⁽¹⁾	45
PLCC-20	43-75(1)	.34
LCC-20	70-80	20 ⁽²⁾
SOIC-16	50-120 ⁽¹⁾	35

(1) Specified Θ_{JA} (junction to ambient) is for devices mounted to $\sin^2 FR4$ PC board with one ounce copper where noted. When resistance range is given, lower values are for \sin^2 aluminum PC board. Test PWB was 0.062in thick and typically used 0.635mm trace widths for power packages and 1.3mm trace widths for non-power packages with 100 x 100 mil probe land area at the end of each trace.

(2) Θ_{JC} data values stated were derived from MIL-STD-1835B. MIL-STD-1835B states that the baseline values shown are worst case (mean +2s) for a 60 x 60mil microcircuit device silicon die and applicable for devices with die sizes up to 14400 square mils. For device die sizes greater than 14400 square mils use the following values; dual-in-line, 11°C/W; flat pack 10°C/W; pin grid array, 10°C/W.

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PARAMETERS	TEST CONDITIONS	UC1825 UC2825			UC3825			TW
WW 100Y.	M.TW WT.1001.	MIN	TOP	MAX	MIN	TOP	MAX	UNITS
Reference Section	CONTRACTOR WWW.		WT	-	MM.	1100	1.00	MT.M
Output Voltage	$To = 25^{\circ}C$, $Io = 1mA$	5.05	5.10	5.15	5.00	5.10	5.20	V
Line Regulation	10V < Vcc < 30V	100	2	20		2	20	mV
Load Regulation	1mA < Io < 10mA	N	5	20		5	20	mV
Temperature Stability*	TMIN < TA < TMAX	N.C.	0.2	0.4	7	0.2	0.4	mV/°C
Total Output Variation*	Line, Load, Temperature	5.00	OMr.	5.20	4.95	MN.	5.25	V
Output Noise Voltage*	10Hz < f < 10kHz	00 -	50			50	100	μV
Long Term Stability*	TJ = 125°C, 1000hrs.	1001.	5	25		5	25	mV
Short Circuit Current	VREF = 0V	-15	-50	-100	-15	-50	-100	mA
Oscillator Section	W.100 CONV.	N.10-		11.			M.	
Initial Accuracy*	TJ = 2°C	360	400	440	360	400	440	kHz
Voltage Stability*	10V < Vcc < 30V	-110	0.2	2		0.2	2	%
Temperature Stability*	TMIN < TA < TMAX	144.5	5	OT T	Z	5	Lev .	%
Total Variation*	Line, Temperature	340		460	340		460	kHz
Oscillator Section (cont.)	N TUNI 1001. CONLTV	W	100 .	COM				N.100
Clock Out High	V WILLOOY.CO. TW	3.9	4.5		3.9	4.5	W.	V
Clock Out Low	WWW.LOON.COM	WW	2.3	2.9	77.	2.3	2.9	V
Ramp Peak*	COM.	2.6	2.8	3.0	2.6	2.8	3.0	V
Ramp Valley*	WWW 1002. OM.TW	0.7	1.0	1.25	0.7	1.0	1.25	V
Ramp Valley to Peak*	WWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWW	1.6	1.8	2.0	1.6	1.8	2.0	V
Error Amplifier Section	WWW.LCONT.	1	MM.	.Yoo	CON	WT		NW.
Input Offset Voltage	N.100 - COM.1	4	WW	10	COM		15	mV
Input Bias Current	WWW 100Y.COM.TW		0.6	3	100	0.6	3	μA
Input Offset Current	WWWWWWWWWWWWWW		0.1	100	1.00	0.1	1	μA
Open Loop Gain	1V < Vo < 4V	60	95	N	60	95	N	dB
CMRR	1.5V < VCM < 5.5V	75	95	V.IU	75	95	-	dB
PSRR	10V < Vcc < 30V	85	110		85	110		dB
Output Sink Current	VPIN 3 = 1V	1	2.5	N	. 11.	2.5	TN	mA
Output Source Current	VPIN 3 = 4V	-0.5	-1.3	NW	-0.5	-1.3	W	mA
Output High Voltage	IPIN 3 = -0.5mA	4.0	4.7	5.0	4.0	4.7	5.0	V
Output Low Voltage	IPIN 3 = 1mA	0	0.5	1.0	000	0.5	1.0	V
Unity Gain Bandwidth*	WWW. avy.COP	3	5.5	MM	3	5.5	11	MHz
Slew Rate*	0.1001	6	12		6	12	OM.	V/µs



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PARAMETERS	TEST CONDITIONS	UC1825 UC2825			UC3825			L.M.
	OM.TW WTW.100Y.C	MIN	TOP	MAX	MIN	TOP	MAX	UNITS
PWM Comparator Section	TW WWW 100Y.	M	TW		N.	N 100		M.T.V
Pin 7 Bias Current	VPIN 7 = 0V	COM	-1	-5	NN	-1 0	-5	μA
Duty Cycle Range	COM-1	0	1	80	0	N.10	85	%
Pin 3 Zero DC Threshold	VPIN 7 = 0V	1.1	1.25	-1	1.1	1.25	10 -	V
Delay to Output*	NY.CO. TW WMITTO	DY.C	50	80	Z	50	80	ns
Soft-Start Section	NCOM. WWW.	O.V.C	One	W	V	M	Yant	.Co.
Charge Current	VPIN 8 = 0.5V	3	9	20	3	9	20	μA
Discharge Current	VPIN 8 = 1V	101.	Mon	T.	1		N.100	mA
Current Limit / Shutdown S	ection	1001		WILL		. An	-10	1.0
Pin 9 Bias Current	0 < VPIN 9 < 4V		V.COr	15		W	10	μA
Current Limit Threshold	W.100 COM. T	0.9	1.0	1.1	0.9	1.0	1.1	V
Shutdown Threshold	1002.001.71	1.25	1.40	1.55	1.25	1.40	1.55	V
Delay to Output	N. W. CO. TW W		50	80	N I	50	80	ns
Output Section	WW.LOW CONL.	MN.,	N.	COM	W		NWN	
Output Low Level	IOUT = 20mA	WAR	0.25	0.40		0.25	0.40	V
	IOUT = 200mA		1.2	2.2	T.L.A.	1.2	2.2	V
Output High Level	IOUT = -20mA	13.0	13.5	1.00	13.0	13.5	NN	V
	IOUT = -200mA	12.0	13.0	V.CO	12.0	13.0	N	V
Collector Leakage	Vc = 30V		100	500	DN',	10	500	μΑ
Rise/Fall Time*	CL = 1nF		30	60	M	30	60	ns
Under-Voltage Lockout Sec	tion	V	N VI	.Yoox.		WT		MM.
Start Threshold	NNN.IN. COM.	8.8	9.2	9.6	8.8	9.2	9.6	V
UVLO Hysteresis	W. 1001. OM.I.	0.4	0.8	1.2	0.4	0.8	1.2	V
Supply Current Section	WWW 100Y.COMTW	•	21 M	100		M.T.V	1	N
Start Up Current	Vcc = 8V		1.1	2.5	N.CU	1.1	2.5	mA
	$V_{\text{DIN},4}$ $V_{\text{DIN},7}$ $V_{\text{DIN},0} = 0V_{1}^{\prime}$ $V_{\text{DIN},0} = 1V_{1}^{\prime}$	-	22	33		22	- 33	mA

* This parameter not 100% tested in production but guaranteed by design. WWW.1007 WWW.100Y.COM.T

Printed Circuit Board Layout Considerations

High speed circuits demand careful attention to layout and component placement. To assure proper performance of the UC1825 follow these rules: 1) Use a ground plane. 2) Damp or clamp parasitic inductive kick energy from the gate of driven MOSFETs. Do not allow the output pins to ring below ground. A series gate resistor or a shunt 1 Amp Schottky diode at the output pin will serve

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this purpose. 3) Bypass VCC, VC, and VREF. Use 0.1μ F monolithic ceramic capacitors with low equivalent series inductance. Allow less than 1 cm of total lead length for each capacitor between the bypassed pin and the ground plane. 4) Treat the timing capacitor, CT, like a bypass capacitor.

Error Amplifier Circuit







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Oscillator Circuit





Synchronized Operation





Constant Volt-Second Clamp Circuit

The circuit shown here will achieve a constant volt-second product clamp over varying input voltages. The ramp generator components, RT and CR are chosen so that the ramp at Pin 9 crosses the 1V threshold at the same time the desired maximum volt-second product is reached. The delay through the functional nor block must be such that the ramp capacitor can be completely discharged during the minimum deadtime.



Output Section









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